# 2SA1365

FOR HIGH CURRENT DRIVE APPLICATION SILICON PNP EPITAXIAL TYPE

### **DESCRIPTION**

2SA1365 is a super mini silicon PNP epitaxial type transistor designed with high collector current, small Vce(sat). Complementary with 2SC3440.

### **FEATURE**

•Low collector to emitter saturation voltage.

VCE(sat)=-0.2V typ

- Excellent linearity of DC forward current gain.
- Super mini package for easy mounting.
- High collector current IcM=-1A
- High gain band width product fT=180MHz typ

# **APPLICATION**

Small type motor drive, relay drive, power supply.

# MAXIMUM RATINGS(Ta=25°C)

Parameter	Symbol	Ratings	Unit	
Collector to Base voltage	V <sub>CBO</sub>	-25	٧	
Emitter to Base voltage	V <sub>EBO</sub>	-4	٧	
Collector to Emitter voltage	V <sub>CEO</sub>	-20	V	
Peak Collector current	I <sub>CM</sub>	-1	Α	
Collector current	I <sub>C</sub>	-700	mA	
Collector dissipation		200	mW	
(Ta=25°C)	P <sub>c</sub>	<b>※</b> 350	ITIVV	
Junction temperature	T <sub>j</sub>	+150	°C	
Storage temperature	$T_{stg}$	-55~+150	°C	

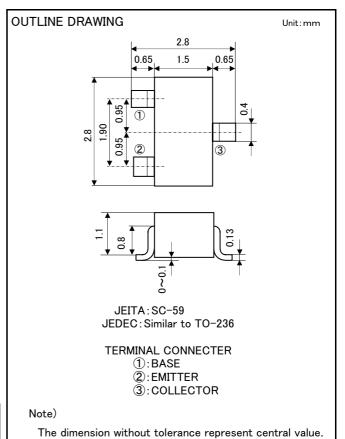
 $\mbox{\ensuremath{\%}}$  package mounted on substrate.

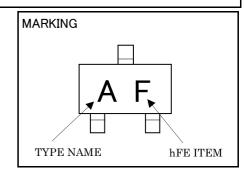
# ELECTRICAL CHARACTERISTICS (Ta=25°C)

Parameter	Symbol	Test conditions	Limits			Unit
			Min	Тур	Max	Unit
C to B breakdown voltage	V(BR)cво	$I_{C}=-10 \mu A$ , $I_{E}=0$	-25	ı	-	٧
E to B breakdown voltage	V(BR) <sub>EBO</sub>	$I_{E}$ =-10 $\mu$ A , $I_{C}$ =0	-4	-	-	٧
C to E breakdown voltage	V(BR)ceo	$I_{C}=-100 \mu A, R_{BE}=\infty$	-20	1	-	V
Collector cut off current	ICBO	$V_{CB}$ =-25V, $I_{E}$ =0	ı	-	-1	μΑ
Emitter cut off current	IEBO	$V_{EB}$ =-2V, I $_{C}$ =0	-	-	-1	μΑ
DC forward current gain	hFE	V <sub>CE</sub> =-4V, I <sub>C</sub> =-100mA	150	1	800	-
C to E Saturation Vlotage	VCE(sat)	I $_{\text{C}}$ =-500mA , $I_{\text{B}}$ =-25mA	-	-0.2	-0.5	٧
Gain band width product	fT	V <sub>CE</sub> =-6V, I <sub>E</sub> =10mA	100	180	-	MHz

### X) It shows hFE classification in below table

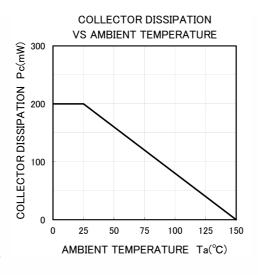
Marking	AE	AF	AG
hFE	150 to 300	250 to 500	400 to 800

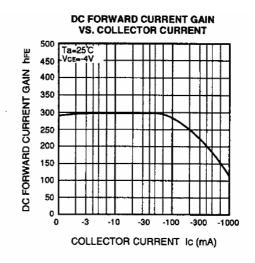


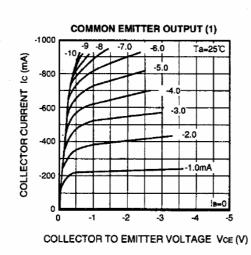


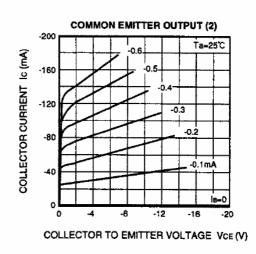
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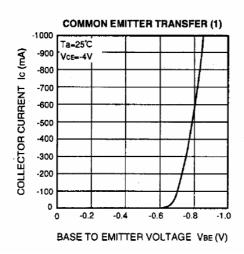
#### TYPICAL CHARACTERISTICS

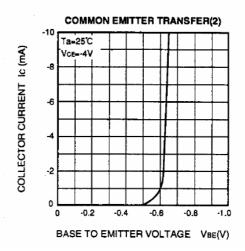














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